

RELIABILITY REPORT
FOR
MAX8643AETG+

PLASTIC ENCAPSULATED DEVICES

March 31, 2009

# **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by				
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Quality Assurance				
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#### Conclusion

The MAX8643AETG+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim"s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim"s quality and reliability standards.

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## I. Device Description

#### A. General

The MAX8643A high-efficiency switching regulator delivers up to 3A load current at output voltages from 0.6V to (0.9 x VIN). The IC operates from 2.35V to 3.6V, making it ideal for on-board point-of-load and postregulation applications. Total output error is less than ±1% over load, line, and temperature. The MAX8643A features fixed-frequency PWM mode operation with a switching frequency range of 500kHz to 2MHz set by an external resistor. High-frequency operation allows for an all-ceramic capacitor design. The high operating frequency also allows for small-size external components. The low-resistance on-chip nMOS switches ensure high efficiency at heavy loads while minimizing critical inductances, making the layout a much simpler task with respect to discrete solutions. Following a simple layout and footprint ensures first-pass success in new designs. The MAX8643A comes with a high-bandwidth (> 14MHz) voltage-error amplifier. The voltage-mode control architecture and the voltage-error amplifier permit a type III compensation scheme to be utilized to achieve maximum loop bandwidth, up to 20% of the switching frequency. High loop bandwidth provides fast transient response, resulting in less required output capacitance and allowing for all-ceramic capacitor designs. The MAX8643A provides two tri-state logic inputs to select one of nine preset output voltages. The preset output voltages allow customers to achieve ±1% output-voltage accuracy without using expensive 0.1% resistors. In addition, the output voltage can be set to any customer value by either using two external resistors at the feedback with 0.6V internal reference or applying an external reference voltage to the REFIN input. The MAX8643A offers programmable soft-start time using one capacitor to reduce input inrush current. The MAX8643A is available in a lead-free, 24-pin, 4mm x 4mm thin QFN package. For assistance with selecting appropriate capacitors, resistors, and inductors, try our online component selection spreadsheet.



## II. Manufacturing Information

A. Description/Function: 3A, 2MHz Step-Down Regulator with Integrated Switches

B. Process: S4

C. Number of Device Transistors:

D. Fabrication Location: Texas

E. Assembly Location: ASAT China, UTL Thailand, Unisem Malaysia

F. Date of Initial Production: April 22, 2006

## III. Packaging Information

A. Package Type: 24-pin TQFN 4x4

B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin
D. Die Attach: Conductive Epoxy
E. Bondwire: Gold (2 mil dia.)
F. Mold Material: Epoxy with silica filler
G. Assembly Diagram: #05-9000-1983
H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per Level 1

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 48°C/W
K. Single Layer Theta Jc: 2.7°C/W
L. Multi Layer Theta Ja: 36°C/W
M. Multi Layer Theta Jc: 2.7°C/W

### IV. Die Information

A. Dimensions: 78 X 71 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub>/SiO<sub>2</sub> (Silicon nitride/ Silicon dioxide

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
 F. Minimum Metal Spacing: Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.
H. Isolation Dielectric: SiO<sub>2</sub>
I. Die Separation Method: Wafer Saw



#### V. Quality Assurance Information

A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)

Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm
D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}}$$
 =  $\frac{1.83}{192 \times 4340 \times 48 \times 2}$  (Chi square value for MTTF upper limit)

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$x = 22.4 \times 10^{-9}$$

3 = 22.4 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at http://www.maxim-ic.com/. Current monitor data for the S4 Process results in a FIT Rate of 4.6 @ 25C and 79.2 @ 55C (0.8 eV, 60% UCL)

## B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

## C. E.S.D. and Latch-Up Testing

The PP34 die type has been found to have all pins able to withstand a transient pulse of

HBM ESD: +/-1000V per JESD22-A114 CDM ESD: +/-1000V per JESD22-C101

Latch-Up testing has shown that this device withstands a current of +/-250 ma, 1.5x VCCMax Overvoltage per JESD78.



## Table 1

## Reliability Evaluation Test Results

## MAX8643AETG+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	48	0	
	Biased Time = 192 hrs.	& functionality			
Moisture Testing	(Note 2)				
85/85	Ta = 85°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 1000hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010				

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data